TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

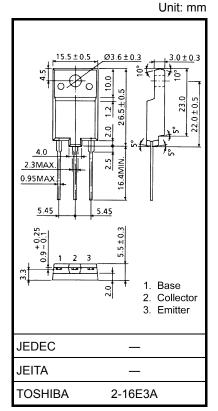
S2000N

COLOR TV HORIZONTAL OUTPUT APPLICATIONS COLOR TV SWITCHING REGULATOR APPLICATIONS

- High Voltage : VCES = 1500 V
- High Speed : $t_f = 0.7 \mu s$ (Max.)
- Low Saturation Voltage : V_{CE} (sat) = 5 V (Max.)
- Collector Metal (Fin) is Fully Covered with Mold Resin.

ABSOLUTE MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTICS		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V _{CES}	1500	V	
Emitter-Base Voltage		V _{EBO}	5	V	
Collector Current	DC	Ι _C	8	A	
	Pulse	I _{CP}	15		
Base Current		Ι _Β	4	А	
Collector Power Dissipation		P _C	50	W	
Junction Temperature		Tj	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	
Thermal Resistance		R _{th (j−c)}	2.5	°C / W	



Weight: 5.5 g (typ.)

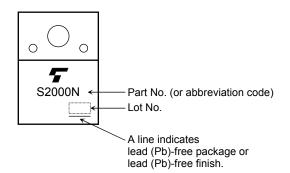
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the

reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

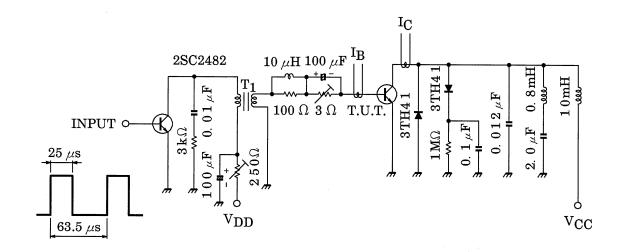
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

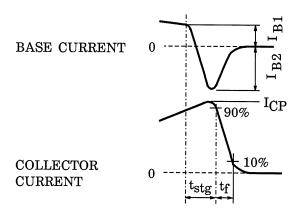
MARKING



ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTICS		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Collector Cut-off Current		I _{CBO}	V _{CB} = 1500 V, V _{BE} = 0	_	—	1	mA
Emitter-Base Breakdown Voltage		V (BR) EBO	I _E = 1 mA, I _C = 0	5	_	_	V
DC Current Gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 A	10	_	30	_
		h _{FE (2)}	V _{CE} = 5 V, I _C = 4.5 A	4.5	_	9	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 4.5 A, I _B = 2 A	_	_	1	v
			I _C = 4.5 A, I _B = 1 A	_	_	5	
Base-Emitter Satura	tion Voltage	V _{BE (sat)}	I _C = 4.5 A, I _B = 1 A	_	0.9	1.2	V
Collector-Emitter Sustain Voltage		V _{CEX (sus)}	L = 40 mH, I _B = 500 mA V _{BE} = -1.7 V	700	_	_	V
Transition Frequency		fT	V _{CE} = 10 V, I _C = 0.1 A	_	2	_	MHz
Collector Output Capacitance		Cob	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	95	_	pF
Switching Time (Fig. 1)	Storage Time	t _{stg}	I _{CP} = 4.5 A, I _{B1} (end) = 1 A f _H = 15.75 kHz	—	8	12	μs
	Fall Time	t _f		_	0.4	0.7	



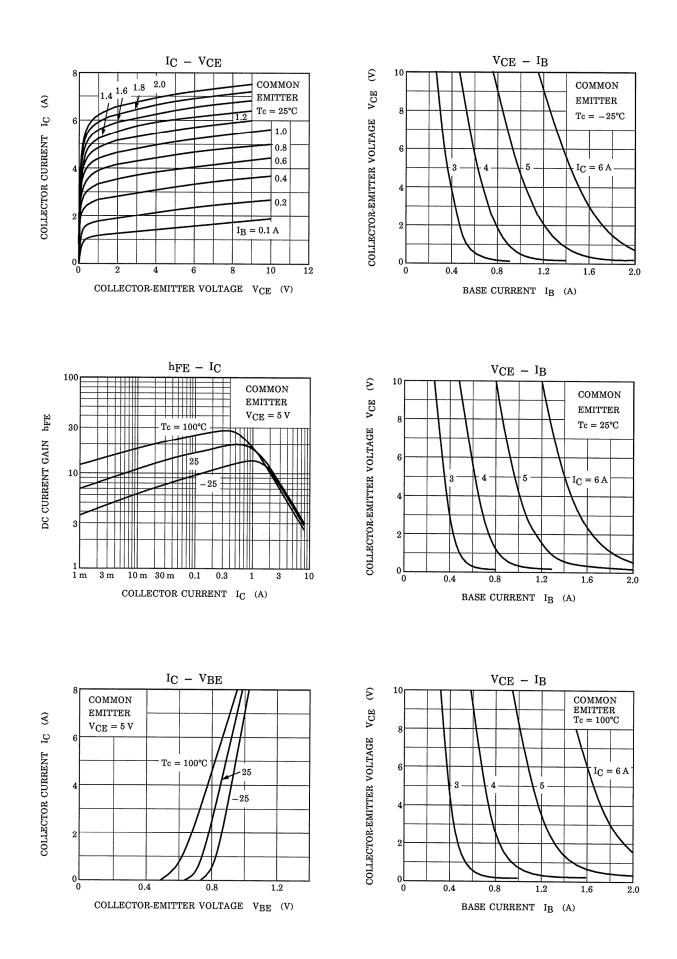


Base Current Gradient

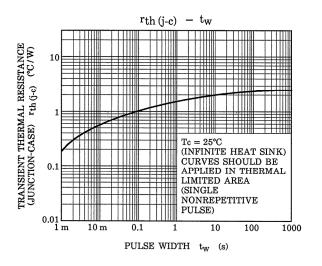
$$dI_{\text{B}} \, / \, dt = \; \frac{I_{B1} + I_{B2}}{t_{stg}} \big(A / \mu \, s \big) \label{eq:dIB}$$

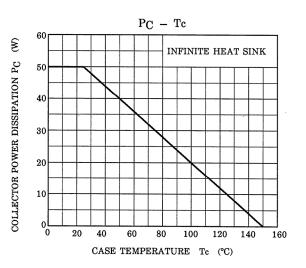
Fig. 1 SWITCHING TIME TEST CIRCUIT

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SAFE OPERATING AREA 50 IC MAX. (PULSED) * 30 TIT 10 μsЖ IC MAX. (PULSED) 💥 00 μs> 1 ms× 10 IC MAX. 5 (CONTINUOUS) Ð 0 ms ŋ 3 DC OPERATION $Tc = 25^{\circ}C$ COLLECTOR CURRENT =100 ms% 0.5 0.3 ※ SINGLE 0.1 NONREPETITIVE PULSE $Tc = 25^{\circ}C$ 50 m CURVES MUST BE DERATED LINEARLY 30 m WITH INCREASE IN VCEX (SUS MAX. TEMPERATURE. 10 mL 1 3 10 30 100 300 1000 COLLECTOR-EMITTER VOLTAGE VCE (V)

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20070701-EN

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